



DS90CF561/DS90CF562 LVDS 18-Bit Color Flat Panel Display (FPD) Link

General Description

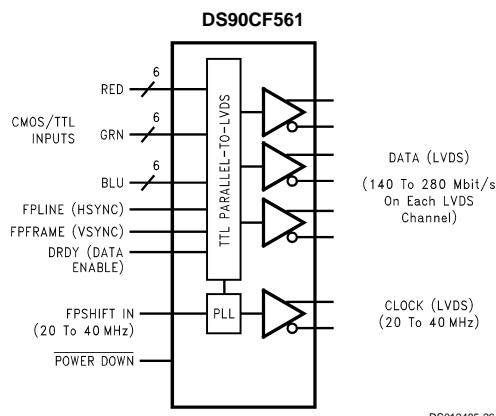
The DS90CF561 transmitter converts 21 bits of CMOS/TTL data into three LVDS (Low Voltage Differential Signaling) data streams. A phase-locked transmit clock is transmitted in parallel with the data streams over a fourth LVDS link. Every cycle of the transmit clock 21 bits of input data are sampled and transmitted. The DS90CF562 receiver converts the LVDS data streams back into 21 bits of CMOS/TTL data. At a transmit clock frequency of 40 MHz, 18 bits of RGB data and 3 bits of LCD timing and control data (FPLINE, FPFRAME, DRDY) are transmitted at a rate of 280 Mbps per LVDS data channel. Using a 40 MHz clock, the data throughput is 105 Megabytes per second. These devices are offered with falling edge data strobes for convenient interface with a variety of graphics and LCD panel controllers.

This chipset is an ideal means to solve EMI and cable size problems associated with wide, high speed TTL interfaces.

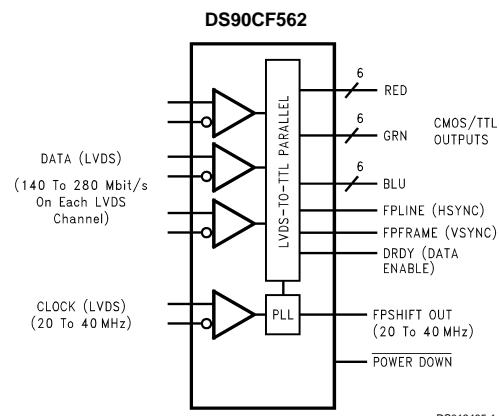
Features

- Up to 105 Megabyte/sec bandwidth
- Narrow bus reduces cable size and cost
- 290 mV swing LVDS devices for low EMI
- Low power CMOS design
- Power down mode
- PLL requires no external components
- Low profile 48-lead TSSOP package
- Falling edge data strobe
- Compatible with TIA/EIA-644 LVDS standard

Block Diagrams



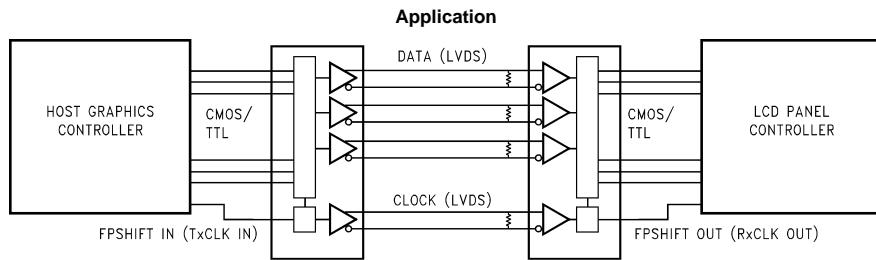
Order Number DS90CF561MTD
See NS Package Number MTD48



Order Number DS90CF562MTD
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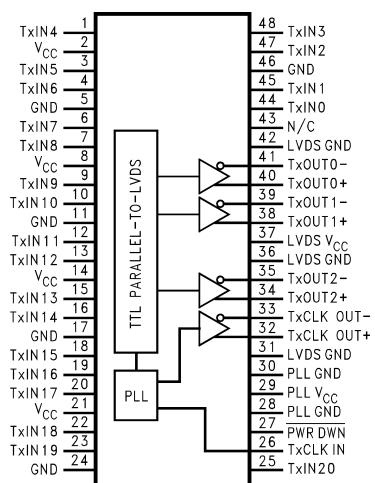
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Block Diagrams (Continued)

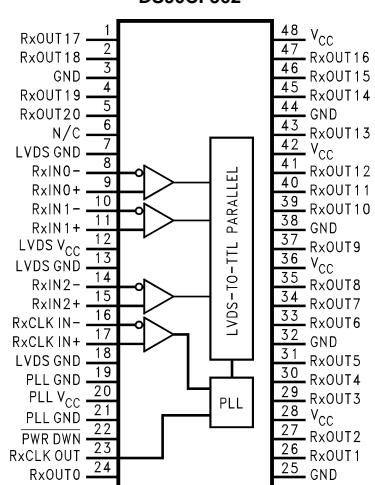


Connection Diagrams

DS90CF561



DS90CF562



Absolute Maximum Ratings (Note 1)		DS90CF561	1.98W
If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.		DS90CF562	1.89W
Supply Voltage (V_{CC})	-0.3V to +6V	Package Derating:	
CMOS/TTL Input Voltage	-0.3V to (V_{CC} + 0.3V)	DS90CF561	16 mW/ $^{\circ}$ C above +25 $^{\circ}$ C
CMOS/TTL Output Voltage	-0.3V to (V_{CC} + 0.3V)	DS90CF562	15 mW/ $^{\circ}$ C above +25 $^{\circ}$ C
LVDS Receiver Input Voltage	-0.3V to (V_{CC} + 0.3V)	This device does not meet 2000V ESD rating (Note 4).	
LVDS Driver Output Voltage	-0.3V to (V_{CC} + 0.3V)		
LVDS Output			
Short Circuit Duration	continuous	Supply Voltage (V_{CC})	Min 4.5 Nom 5.0 Max 5.5 Units V
Junction Temperature	+150 $^{\circ}$ C	Operating Free Air	
Storage Temperature Range	-65 $^{\circ}$ C to +150 $^{\circ}$ C	Temperature (T_A)	Min -10 Nom +25 Max +70 Units $^{\circ}$ C
Lead Temperature (Soldering, 4 sec.)	+260 $^{\circ}$ C	Receiver Input Range	Min 0 Nom 2.4 Max 2.4 Units V
Maximum Power Dissipation @ +25 $^{\circ}$ C		Supply Noise Voltage (V_{CC})	Min 100 Nom 100 Max 100 Units mV _{P-P}
MTD48 (TSSOP) Package:			
Recommended Operating Conditions			
Symbol	Parameter	Conditions	Min Typ Max Units
CMOS/TTL DC SPECIFICATIONS			
V_{IH}	High Level Input Voltage		2.0 V_{CC} V
V_{IL}	Low Level Input Voltage		GND 0.8 V
V_{OH}	High Level Output Voltage	$I_{OH} = -0.4$ mA	3.8 4.9 V
V_{OL}	Low Level Output Voltage	$I_{OL} = 2$ mA	0.1 0.3 V
V_{CL}	Input Clamp Voltage	$I_{CL} = -18$ mA	-0.79 -1.5 V
I_{IN}	Input Current	$V_{IN} = V_{CC}$, GND, 2.5V or 0.4V	± 5.1 ± 10 μ A
I_{OS}	Output Short Circuit Current	$V_{OUT} = 0$ V	-120 mA
LVDS DRIVER DC SPECIFICATIONS			
V_{OD}	Differential Output Voltage	$R_L = 100\Omega$	250 290 450 mV
ΔV_{OD}	Change in V_{OD} between Complimentary Output States		
V_{CM}	Common Mode Voltage		35 mV
ΔV_{CM}	Change in V_{CM} between Complimentary Output States		1.1 1.25 1.375 V
V_{OH}	High Level Output Voltage		
V_{OL}	Low Level Output Voltage		35 mV
I_{OS}	Output Short Circuit Current		1.3 1.6 V
I_{OZ}	Output TRI-STATE® Current	$V_{OUT} = 0$ V, $R_L = 100\Omega$	0.9 1.01 V
		Power Down = 0V, $V_{OUT} = 0$ V or V_{CC}	-2.9 -5 mA
			± 1 ± 10 μ A
LVDS RECEIVER DC SPECIFICATIONS			
V_{TH}	Differential Input High Threshold	$V_{CM} = +1.2$ V	+100 mV
V_{TL}	Differential Input Low Threshold		-100 mV
I_{IN}	Input Current	$V_{IN} = +2.4$ V	± 10 μ A
		$V_{IN} = 0$ V	± 10 μ A
TRANSMITTER SUPPLY CURRENT			
I_{CCTW}	Transmitter Supply Current, Worst Case	$R_L = 100\Omega$, $C_L = 5$ pF, Worst Case Pattern (Figure 1, Figure 3)	$f = 32.5$ MHz 34 51 mA
			$f = 37.5$ MHz 36 53 mA
I_{CCTG}	Transmitter Supply Current, 16 Grayscale	$R_L = 100\Omega$, $C_L = 5$ pF, Grayscale Pattern (Figure 2, Figure 3)	$f = 32.5$ MHz 27 47 mA
			$f = 37.5$ MHz 28 48 mA

Electrical Characteristics (Continued)

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Conditions	Min	Typ	Max	Units
TRANSMITTER SUPPLY CURRENT						
I _{CCTZ}	Transmitter Supply Current, Power Down	Power Down = Low		1	25	μA
RECEIVER SUPPLY CURRENT						
I _{CCRW}	Receiver Supply Current, Worst Case	C _L = 8 pF, Worst Case Pattern (Figure 1, Figure 4)	f = 32.5 MHz		55	mA
			f = 37.5 MHz		60	mA
I _{CCRG}	Receiver Supply Current, 16 Grayscale	C _L = 8 pF, 16 Grayscale Pattern (Figure 2, Figure 4)	f = 32.5 MHz		35	mA
			f = 37.5 MHz		37	mA
I _{CCRZ}	Receiver Supply Current, Power Down	Power Down = Low		1	10	μA

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the device should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.

Note 2: Typical values are given for V_{CC} = 5.0V and T_A = +25°C.

Note 3: Current into device pins is defined as positive. Current out of device pins is defined as negative. Voltages are referenced to ground unless otherwise specified (except V_{OD} and ΔV_{OD}).

Note 4: ESD Rating:

HBM (1.5 kΩ, 100 pF)

PLL V_{CC} ≥ 1000V

All other pins ≥ 2000V

EIAJ (0Ω, 200 pF) ≥ 150V

Transmitter Switching Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Min	Typ	Max	Units
LLHT	LVDS Low-to-High Transition Time (Figure 3)		0.75	1.5	ns
LHLT	LVDS High-to-Low Transition Time (Figure 3)		0.75	1.5	ns
TCIT	TxCLK IN Transition Time (Figure 5)			8	ns
TCSS	TxOUT Channel-to-Channel Skew (Note 5) (Figure 6)			350	ps
TPPos0	Transmitter Output Pulse Position for Bit 0 (Figure 17)	f = 20 MHz	-200	150	ps
TPPos1	Transmitter Output Pulse Position for Bit 1		6.3	7.2	ns
TPPos2	Transmitter Output Pulse Position for Bit 2		12.8	13.6	ns
TPPos3	Transmitter Output Pulse Position for Bit 3		20	20.8	ns
TPPos4	Transmitter Output Pulse Position for Bit 4		27.2	28	ns
TPPos5	Transmitter Output Pulse Position for Bit 5		34.5	35.2	ns
TPPos6	Transmitter Output Pulse Position for Bit 6		42.2	42.6	ns
TPPos0	Transmitter Output Pulse Position for Bit 0 (Figure 16)	f = 40 MHz	-100	100	ps
TPPos1	Transmitter Output Pulse Position for Bit 1		2.9	3.3	ns
TPPos2	Transmitter Output Pulse Position for Bit 2		6.1	6.6	ns
TPPos3	Transmitter Output Pulse Position for Bit 3		9.7	10.2	ns
TPPos4	Transmitter Output Pulse Position for Bit 4		13	13.5	ns
TPPos5	Transmitter Output Pulse Position for Bit 5		17	17.4	ns
TPPos6	Transmitter Output Pulse Position for Bit 6		20.3	20.8	ns
TCIP	TxCLK IN Period (Figure 7)		25	T	ns
TCIH	TxCLK IN High Time (Figure 7)		0.35T	0.5T	0.65T
TCIL	TxCLK IN Low Time (Figure 7)		0.35T	0.5T	0.65T
TSTC	TxIN Setup to TxCLK IN (Figure 7)	f = 20 MHz	14		ns
		f = 40 MHz	8		ns
THTC	TxIN Hold to TxCLK IN (Figure 7)		2.5	2	ns

Transmitter Switching Characteristics (Continued)

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Min	Typ	Max	Units
TCCD	TxCLK IN to TxCLK OUT Delay @ 25°C, $V_{CC} = 5.0V$ (<i>Figure 9</i>)	5		9.7	ns
TPLLS	Transmitter Phase Lock Loop Set (<i>Figure 11</i>)			10	ms
TPDD	Transmitter Powerdown Delay (<i>Figure 15</i>)			100	ns

Note 5: This limit based on bench characterization.

Receiver Switching Characteristics

Over recommended operating supply and temperature ranges unless otherwise specified

Symbol	Parameter	Min	Typ	Max	Units
CLHT	CMOS/TTL Low-to-High Transition Time (<i>Figure 4</i>)		3.5	6.5	ns
CHLT	CMOS/TTL High-to-Low Transition Time (<i>Figure 4</i>)		2.7	6.5	ns
RCOP	RxCLK OUT Period (<i>Figure 8</i>)	25	T	50	ns
RSKM	Receiver Skew Margin (Note 6). $V_{CC} = 5V$, $T_A = 25^\circ C$ (<i>Figure 18</i>)	$f = 20$ MHz	1.1		ns
		$f = 40$ MHz	700		ps
RCOH	RxCLK OUT High Time (<i>Figure 8</i>)	$f = 20$ MHz	21.5		ns
		$f = 40$ MHz	10.5		ns
RCOL	RxCLK OUT Low Time (<i>Figure 8</i>)	$f = 20$ MHz	19		ns
		$f = 40$ MHz	6		ns
RSRC	RxOUT Setup to RxCLK OUT (<i>Figure 8</i>)	$f = 20$ MHz	14		ns
		$f = 40$ MHz	4.5		ns
RHRC	RxOUT Hold to RxCLK OUT (<i>Figure 8</i>)	$f = 20$ MHz	16		ns
		$f = 40$ MHz	6.5		ns
RCCD	RxCLK IN to RxCLK OUT Delay @ 25°C, $V_{CC} = 5.0V$ (<i>Figure 10</i>)	7.6		11.9	ns
RPLLS	Receiver Phase Lock Loop Set (<i>Figure 12</i>)			10	ms
RPDD	Receiver Powerdown Delay (<i>Figure 16</i>)			1	μs

Note 6: Receiver Skew Margin is defined as the valid data sampling region at the receiver inputs. This margin takes into account for transmitter output skew(TCCS) and the setup and hold time (internal data sampling window), allowing LVDS cable skew dependent on type/length and source clock(TxCLK IN) jitter.

$RSKM \geq$ cable skew (type, length) + source clock jitter (cycle to cycle)

AC Timing Diagrams

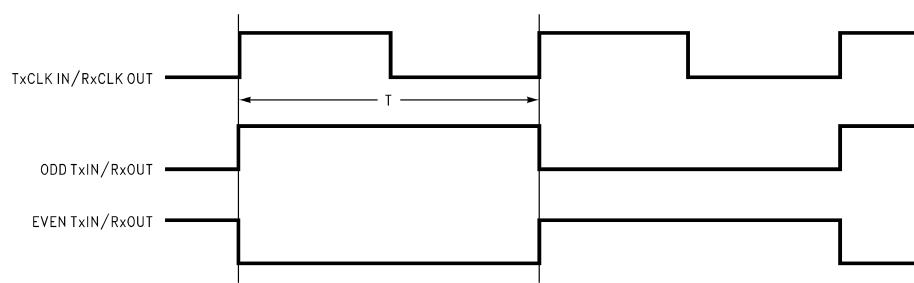


FIGURE 1. "Worst Case" Test Pattern

DS012485-5

AC Timing Diagrams (Continued)

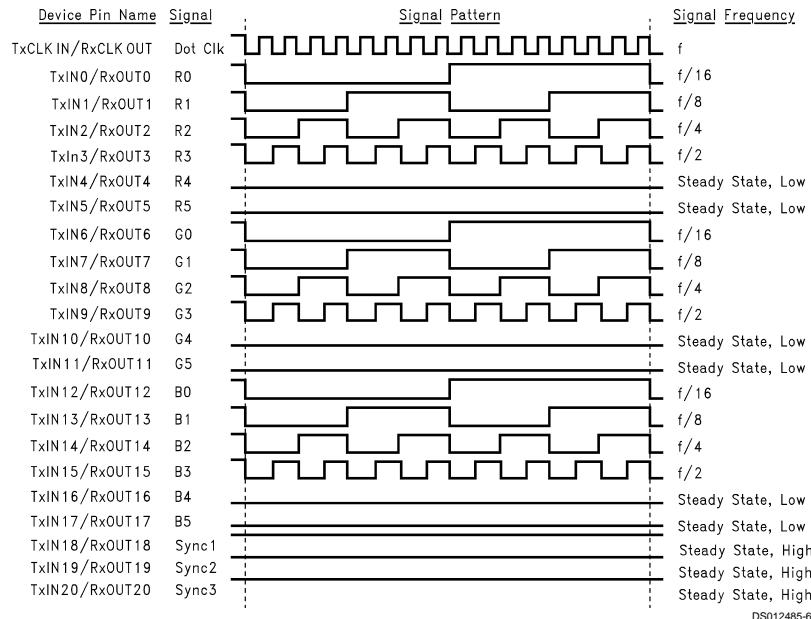


FIGURE 2. "16 Grayscale" Test Pattern (Notes 7, 8, 9, 10)

Note 7: The worst case test pattern produces a maximum toggling of device digital circuitry, LVDS I/O and TTL I/O.

Note 8: The 16 grayscale test pattern tests device power consumption for a "typical" LCD display pattern. The test pattern approximates signal switching needed to produce groups of 16 vertical stripes across the display.

Note 9: Figure 1 and Figure 2 show a falling edge data strobe (TxCLK IN/RxCLK OUT).

Note 10: Recommended pin to signal mapping. Customer may choose to define differently.

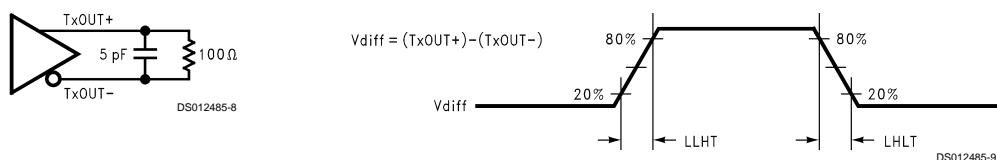


FIGURE 3. DS90CF561 (Transmitter) LVDS Output Load and Transition Timing

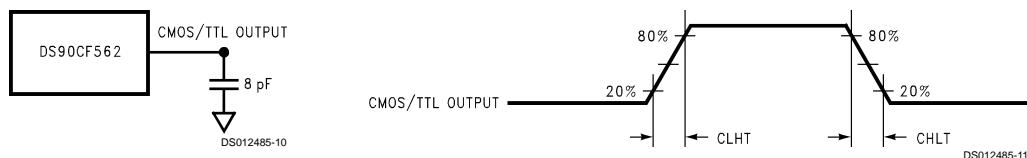


FIGURE 4. DS90CF562 (Receiver) CMOS/TTL Output Load and Transition Timing

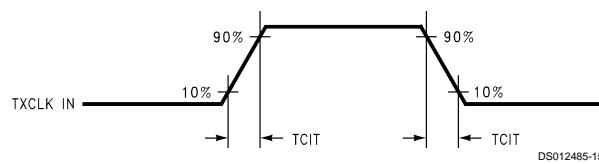
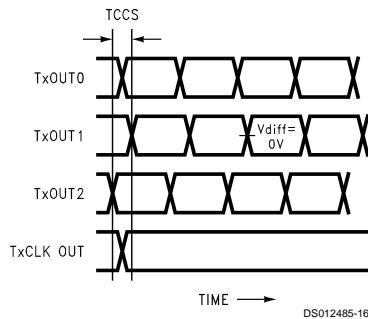


FIGURE 5. DS90CF561 (Transmitter) Input Clock Transition Time

AC Timing Diagrams (Continued)



Measurements at $V_{diff} = 0V$

TCCS measured between earliest and latest initial LVDS edges.
TxCLK OUT Differential High→Low Edge for DS90CF561
TxCLK OUT Differential Low→High Edge for DS90CR561

FIGURE 6. DS90CF561 (Transmitter) Channel-to-Channel Skew and Pulse Width

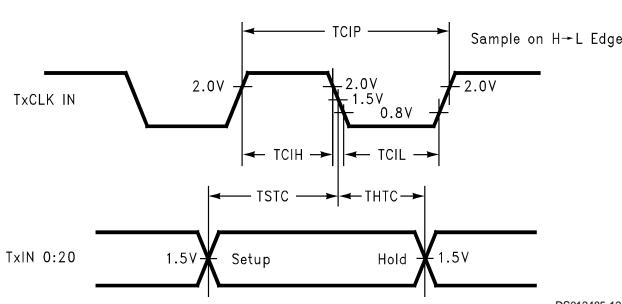


FIGURE 7. DS90CF561 (Transmitter) Setup/Hold and High/Low Times

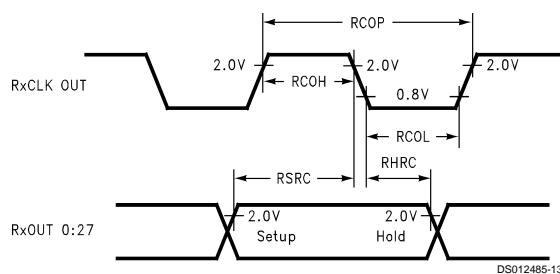


FIGURE 8. DS90CF562 (Receiver) Setup/Hold and High/Low Times

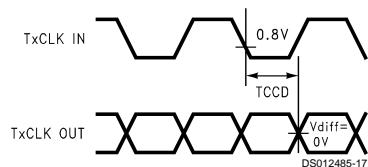


FIGURE 9. DS90CF561 (Transmitter) Clock In to Clock Out Delay

AC Timing Diagrams (Continued)

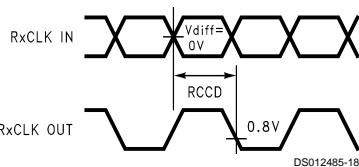


FIGURE 10. DS90CF562 (Receiver) Clock In to Clock Out Delay

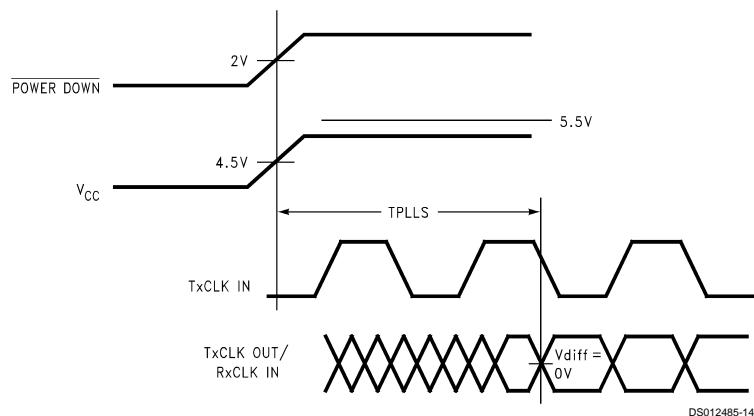


FIGURE 11. DS90CF561 (Transmitter) Phase Lock Loop Set Time

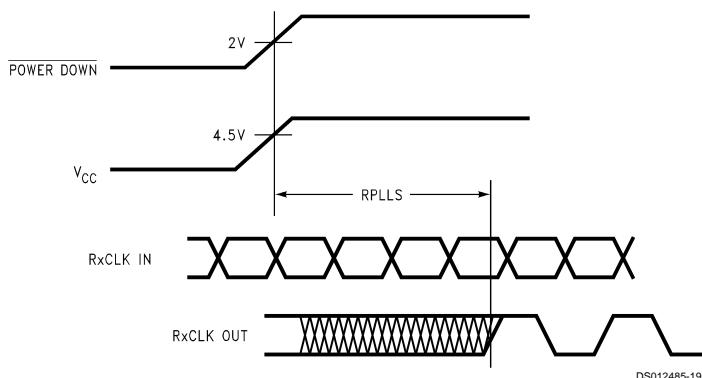


FIGURE 12. DS90CF562 (Receiver) Phase Lock Loop Set Time

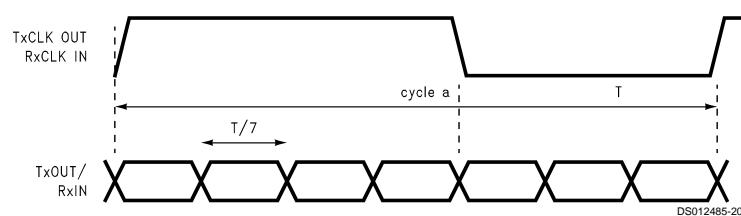


FIGURE 13. Seven Bits of LVDS in One Clock Cycle

AC Timing Diagrams (Continued)

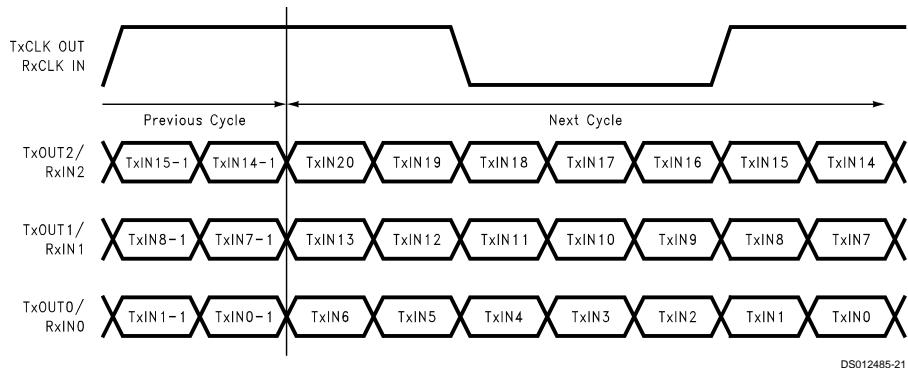


FIGURE 14. 21 Parallel TTL Data Inputs Mapped to LVDS Outputs (DS90CF561)

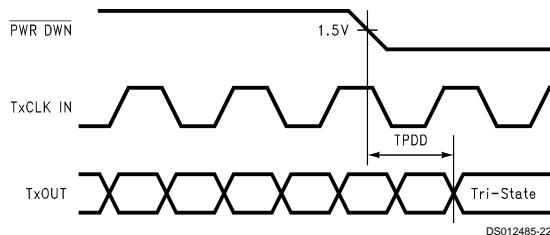


FIGURE 15. Transmitter Powerdown Delay

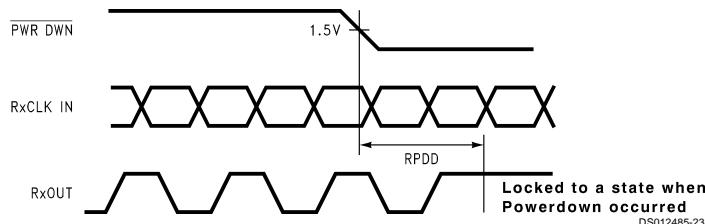


FIGURE 16. Receiver Powerdown Delay

AC Timing Diagrams (Continued)

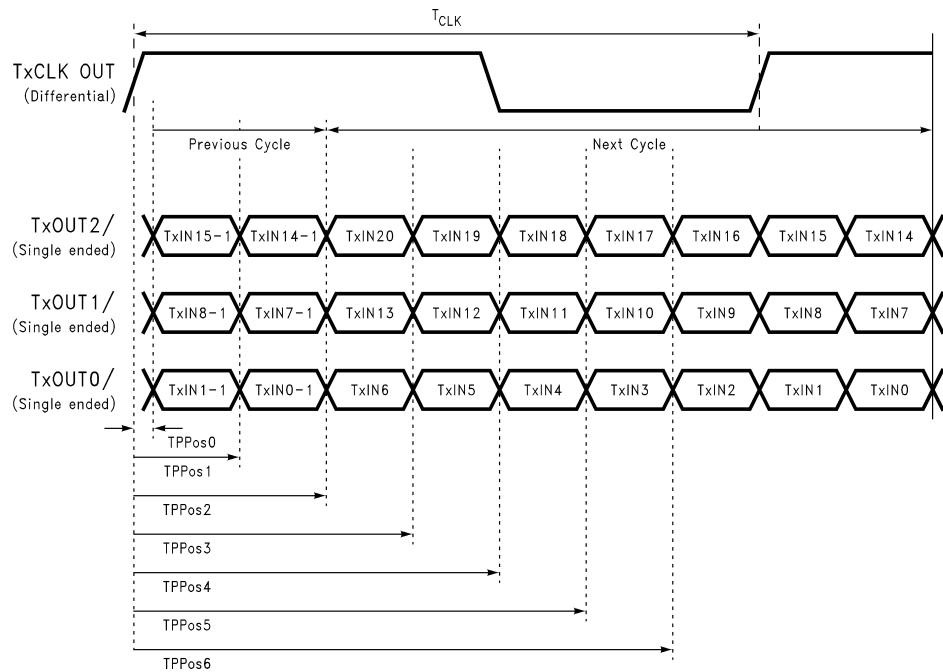
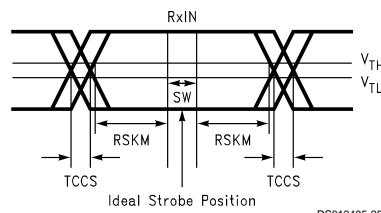


FIGURE 17. Transmitter LVDS Output Pulse Position Measurement

DS012485-24



DS012485-25

SW — Setup and Hold Time (Internal Data Sampling Window)

TCCS — Transmitter Output Skew

$RSKM \geq$ Cable Skew (Type, Length) + Source Clock Jitter (Cycle to Cycle)

Cable Skew — Typically 10 ps–40 ps per foot

FIGURE 18. Receiver LVDS Input Skew Margin

DS90CF561 Pin Description—FPD Link Transmitter

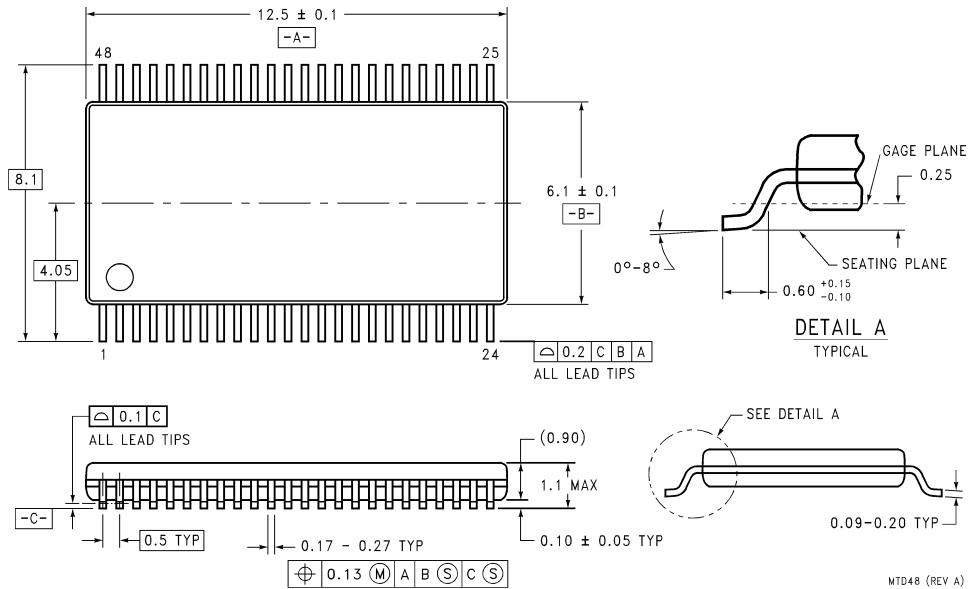
Pin Name	I/O	No.	Description
TxIN	I	21	TTL level input. This includes: 6 Red, 6 Green, 6 Blue, and 3 control lines (FPLINE, FPFRAME, DRDY). (Also referred to as HSYNC, VSYNC and DATA ENABLE.)
TxOUT+	O	3	Positive LVDS differential data output
TxOUT-	O	3	Negative LVDS differential data output
FPSHIFT IN	I	1	TTL level clock input. The falling edge acts as data strobe.
TxCLK OUT+	O	1	Positive LVDS differential clock output
TxCLK OUT-	O	1	Negative LVDS differential clock output
PWR DOWN	I	1	TTL level input. Assertion (low input) TRI-STATES the outputs, ensuring low current at power down.
V _{CC}	I	4	Power supply pins for TTL inputs
GND	I	5	Ground pins for TTL inputs
PLL V _{CC}	I	1	Power supply pin for PLL
PLL GND	I	2	Ground pins for PLL
LVDS V _{CC}	I	1	Power supply pin for LVDS outputs
LVDS GND	I	3	Ground pins for LVDS outputs

DS90CF562 Pin Description—FPD Link Receiver

Pin Name	I/O	No.	Description
RxIN+	I	3	Positive LVDS differential data inputs
RxIN-	I	3	Negative LVDS differential data inputs
RxOUT	O	21	TTL level data outputs. This includes: 6 Red, 6 Green, 6 Blue, and 3 control lines (FPLINE, FPFRAME, DRDY). (Also referred to as HSYNC, VSYNC and DATA ENABLE.)
RxCLK IN+	I	1	Positive LVDS differential clock input
RxCLK IN-	I	1	Negative LVDS differential clock input
FPSHIFT OUT	O	1	TTL level clock output. The falling edge acts as data strobe.
PWR DOWN	I	1	TTL level input. Assertion (low input) maintains the receiver outputs in the previous state
V _{CC}	I	4	Power supply pins for TTL outputs
GND	I	5	Ground pins for TTL outputs
PLL V _{CC}	I	1	Power supply for PLL
PLL GND	I	2	Ground pin for PLL
LVDS V _{CC}	I	1	Power supply pin for LVDS inputs
LVDS GND	I	3	Ground pins for LVDS inputs

DS90CF561/DS90CF562 LVDS 18-Bit Color Flat Panel Display (FPD) Link

Physical Dimensions inches (millimeters) unless otherwise noted



**48-Lead Molded Thin Shrink Small Outline Package, JEDEC
NS Package Number MTD48**

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2. A critical component in any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.



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